

### FEATURES

- 1.6  $\Omega$  on resistance
- 0.4  $\Omega$  on resistance flatness
- Up to 250 mA continuous current
- Fully specified at 15 V
- No  $V_L$  supply required
- 3 V logic-compatible inputs
- Rail-to-rail operation
- 8-lead 3 mm  $\times$  2 mm LFCSP package

### APPLICATIONS

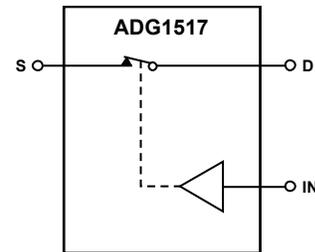
- Audio signal routing
- Video signal routing
- Battery-powered systems
- Communication systems
- Data acquisition systems
- Relay replacement

### GENERAL DESCRIPTION

The ADG1517 is a single-pole/single-throw (SPST) switch. Figure 1 shows that with a logic input of 1, the switch of the ADG1517 is closed. The switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked.

The *i*CMOS™ (industrial CMOS) modular manufacturing process combines high voltage CMOS (complementary metal-oxide semiconductor) and bipolar technologies. It enables the development of a wide range of high performance analog ICs in a footprint that no other generation of high voltage parts has been able to achieve. Unlike analog ICs using conventional CMOS processes, *i*CMOS components can tolerate high supply voltages while providing increased performance, dramatically lower power consumption, and reduced package size.

### FUNCTIONAL BLOCK DIAGRAM



NOTES  
1. SWITCH SHOWN FOR A LOGIC 1 INPUT.

07789-001

Figure 1.

The on resistance profile is very flat over the full analog input range, ensuring excellent linearity and low distortion when switching audio signals. *i*CMOS construction ensures ultralow power dissipation, making the part ideally suited for portable and battery-powered instruments.

### PRODUCT HIGHLIGHTS

1. 1.85  $\Omega$  maximum on resistance at 25°C.
2. Minimum distortion.
3. 3 V logic-compatible digital inputs:  $V_{IH} = 2.0$  V,  $V_{IL} = 0.8$  V.
4. No  $V_L$  logic power supply required.

#### Rev. 0

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

**TABLE OF CONTENTS**

Features .....	1	Absolute Maximum Ratings .....	4
Applications.....	1	Thermal Resistance .....	4
Functional Block Diagram .....	1	ESD Caution.....	4
General Description .....	1	Pin Configuration and Function Descriptions.....	5
Product Highlights .....	1	Typical Performance Characteristics .....	6
Revision History .....	2	Test Circuits.....	8
Specifications.....	3	Terminology .....	10
Single Supply .....	3	Outline Dimensions .....	11
Continuous Current, S or D.....	3	Ordering Guide .....	11

**REVISION HISTORY**

**10/08—Revision 0: Initial Version**

## SPECIFICATIONS

### SINGLE SUPPLY

$V_{DD} = 15\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , unless otherwise noted.

Table 1.

Parameter	25°C	-40°C to +85°C	-40°C to +125°C	Unit	Test Conditions/Comments
<b>ANALOG SWITCH</b>					
Analog Signal Range			0 V to $V_{DD}$	V	
On Resistance ( $R_{ON}$ )	1.6 1.85	2.4	2.75	$\Omega$ typ $\Omega$ max	$V_S = 0\text{ V to }10\text{ V}$ , $I_S = -10\text{ mA}$ ; see Figure 13 $V_{DD} = 13.5\text{ V}$
On Resistance Flatness ( $R_{FLAT(ON)}$ )	0.4 0.5	0.6	0.7	$\Omega$ typ $\Omega$ max	$V_S = 0\text{ V to }10\text{ V}$ , $I_S = -10\text{ mA}$
<b>LEAKAGE CURRENTS</b>					
Source Off Leakage, $I_S$ (Off)	$\pm 10$			nA typ	$V_{DD} = 16.5\text{ V}$ $V_S = 1\text{ V}$ , $V_D = 10\text{ V}$ ; or $V_S = 10\text{ V}$ , $V_D = 1\text{ V}$ ; see Figure 14
Drain Off Leakage, $I_D$ (Off)	$\pm 10$			nA typ	$V_S = 1\text{ V}$ , $V_D = 10\text{ V}$ ; or $V_S = 10\text{ V}$ , $V_D = 1\text{ V}$ ; see Figure 14
Channel On Leakage, $I_D$ , $I_S$ (On)	$\pm 10$			nA typ	$V_S = V_D = 1\text{ V or }10\text{ V}$ , see Figure 15
<b>DIGITAL INPUTS</b>					
Input High Voltage, $V_{INH}$			2.0	V min	
Input Low Voltage, $V_{INL}$			0.8	V max	
Input Current, $I_{INL}$ or $I_{INH}$	0.001		$\pm 0.1$	$\mu\text{A}$ typ $\mu\text{A}$ max	$V_{IN} = V_{GND}$ or $V_{DD}$
Digital Input Capacitance, $C_{IN}$	4			pF typ	
<b>DYNAMIC CHARACTERISTICS<sup>1</sup></b>					
$t_{ON}$	135 175	220	250	ns typ ns max	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ $V_S = 10\text{ V}$ ; see Figure 19
$t_{OFF}$	115 155	190	220	ns typ ns max	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ $V_S = 10\text{ V}$ ; see Figure 19
Charge Injection	70			pC typ	$V_S = 8\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ ; see Figure 20
Off Isolation	-60			dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 16
Total Harmonic Distortion + Noise (THD + N)	0.04			% typ	$R_L = 110\ \Omega$ , $7.5\text{ V p-p}$ , $f = 20\text{ Hz to }20\text{ kHz}$ ; see Figure 18
-3 dB Bandwidth	65			MHz typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ; see Figure 17
Insertion Loss	-0.16			dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 17
$C_S$ (Off)	68			pF typ	$f = 1\text{ MHz}$ ; $V_S = 7.5\text{ V}$
$C_D$ (Off)	68			pF typ	$f = 1\text{ MHz}$ ; $V_S = 7.5\text{ V}$
$C_D$ , $C_S$ (On)	185			pF typ	$f = 1\text{ MHz}$ ; $V_S = 7.5\text{ V}$
<b>POWER REQUIREMENTS</b>					
$I_{DD}$	0.001		1.0	$\mu\text{A}$ typ $\mu\text{A}$ max	$V_{DD} = 16.5\text{ V}$ Digital inputs = 0 V or $V_{DD}$
$I_{DD}$	75		145	$\mu\text{A}$ typ $\mu\text{A}$ max	Digital inputs = 5 V
$V_{DD}$			5/16.5	V min/max	$GND = 0\text{ V}$

<sup>1</sup> Guaranteed by design, not subject to production test.

### CONTINUOUS CURRENT, S OR D

Table 2.

Parameter	25°C	85°C	125°C	Unit	Test Conditions/Comments
CONTINUOUS CURRENT, S or D <sup>1,2</sup>	250	150	100	mA max	$V_{DD} = 13.5\text{ V}$ , $GND = 0\text{ V}$

<sup>1</sup> Guaranteed by design, not subject to production test.

<sup>2</sup> Data based on  $\theta_{JA}$  data shown in Table 4.

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 3.**

Parameter	Rating
$V_{DD}$ to GND	-0.3 V to +25 V
Analog Inputs <sup>1</sup>	GND - 0.3 V to $V_{DD} + 0.3$ V or 30 mA, whichever occurs first
Digital Inputs <sup>1</sup>	GND - 0.3 V to $V_{DD} + 0.3$ V or 30 mA, whichever occurs first
Peak Current, S or D	Data in Table 2 + 10% (pulsed at 1 ms, 10% duty cycle max)
Operating Temperature Range	
Industrial	-40°C to +125°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	150°C
Reflow Soldering Peak Temperature, Pb Free	260°C

<sup>1</sup> Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for a 4-layer board and with the exposed pad soldered to the board.

**Table 4. Thermal Resistance**

Package Type	$\theta_{JA}$	Unit
8-Lead LFCSP (CP-8-4)	50.8	°C/W

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

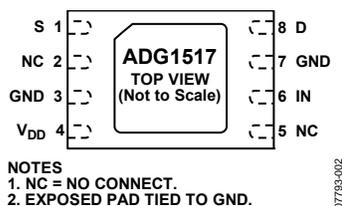


Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	S	Source Terminal. Can be an input or output.
2	NC	No Connect.
3	GND	Ground (0 V) Reference. Both GND pins must be connected to GND potential.
4	V <sub>DD</sub>	Most Positive Power Supply Potential.
5	NC	No Connect.
6	IN	Logic Control Input.
7	GND	Ground (0 V) Reference. Both GND pins must be connected to GND potential.
8	D	Drain Terminal. Can be an input or output.
9 (EPAD)	Exposed Paddle (EPAD)	The exposed paddle should be tied to GND.

Table 6. Truth Table

ADG1517 IN Pin	Switch Condition
1	On
0	Off

## TYPICAL PERFORMANCE CHARACTERISTICS

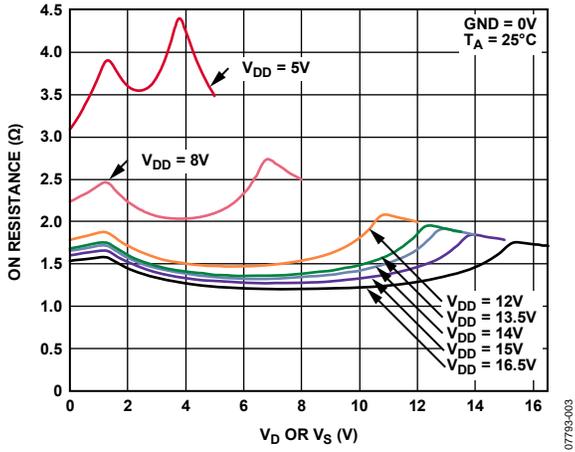


Figure 3. On Resistance as a Function of  $V_D$  or  $V_S$  for Single Supply

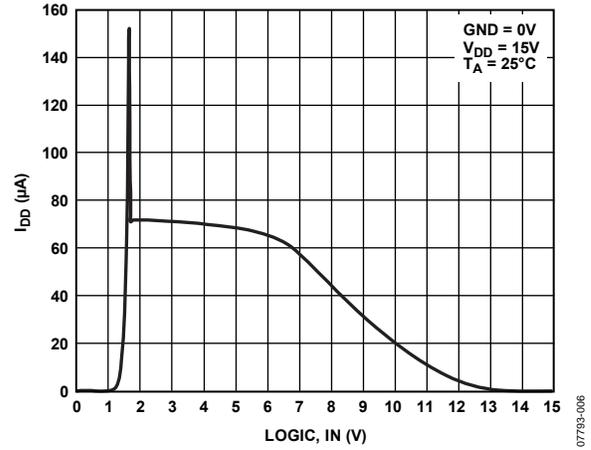


Figure 6.  $I_{DD}$  vs. Logic Level

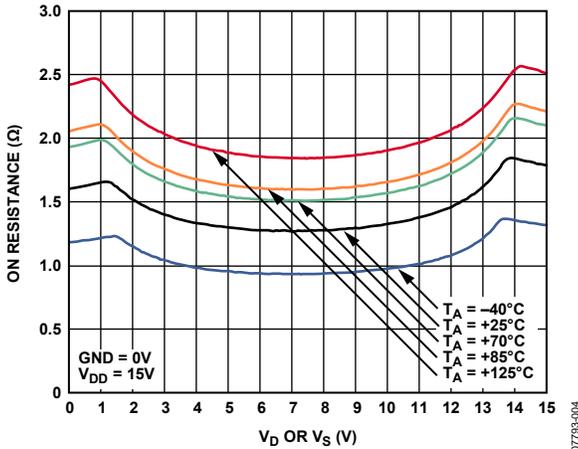


Figure 4. On Resistance as a Function of  $V_D$  or  $V_S$  for Different Temperatures, Single Supply

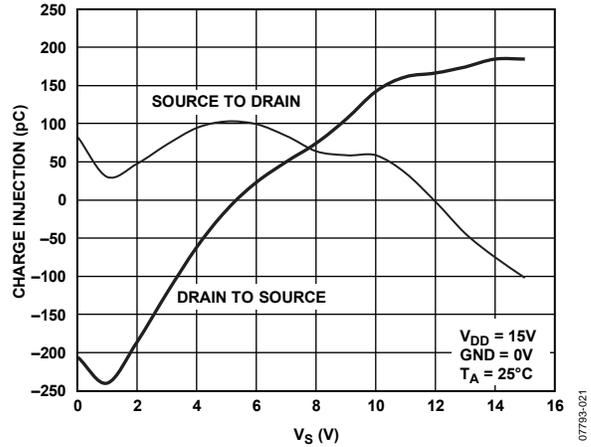


Figure 7. Charge Injection vs. Source Voltage

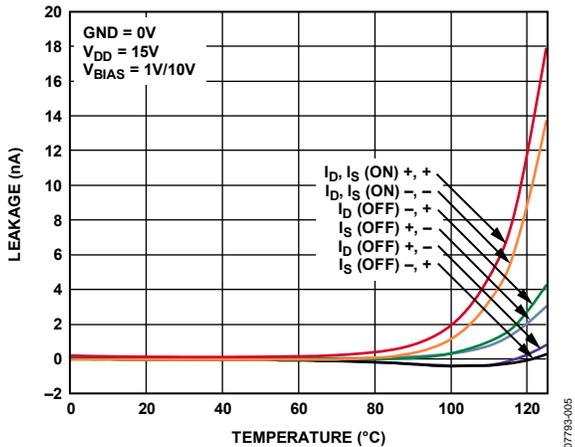


Figure 5. Leakage Currents as a Function of Temperature, Single Supply

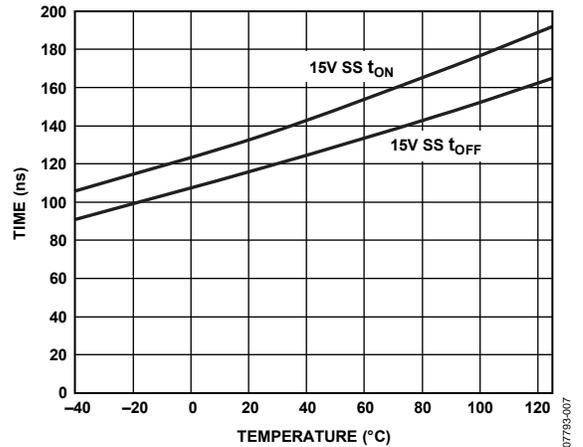


Figure 8.  $t_{ON}/t_{OFF}$  Times vs. Temperature

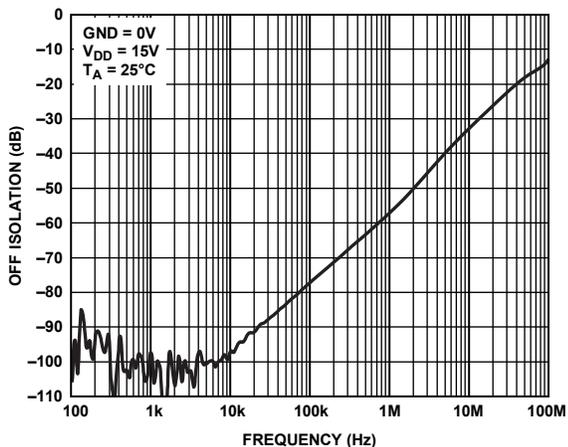


Figure 9. Off Isolation vs. Frequency

07793-008

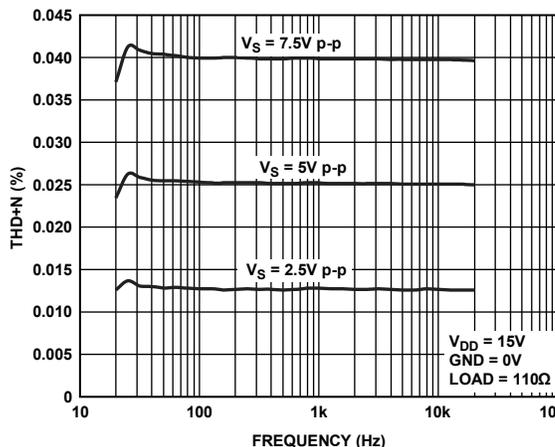


Figure 11. THD + N vs. Frequency

07793-022

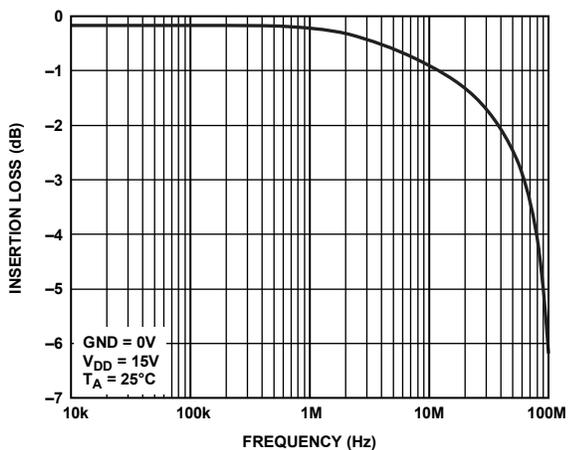


Figure 10. On Response vs. Frequency

07793-009

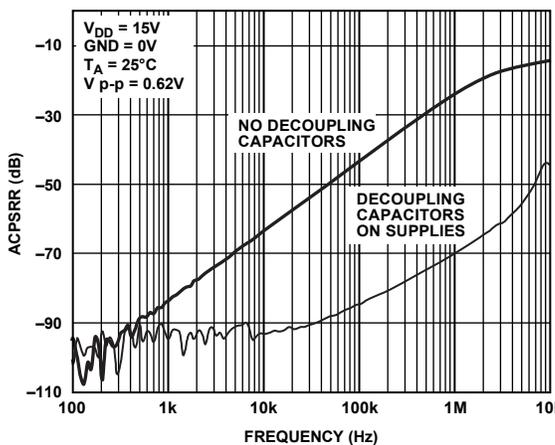


Figure 12. ACPSRR vs. Frequency

07793-011

## TEST CIRCUITS

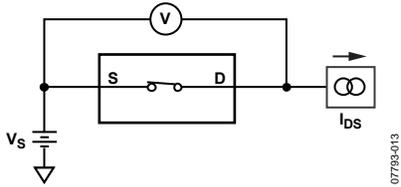


Figure 13. On Resistance

07793-013

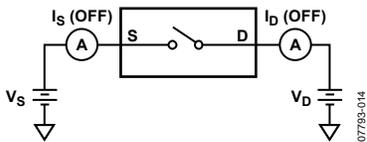


Figure 14. Off Resistance

07793-014

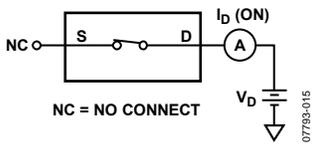
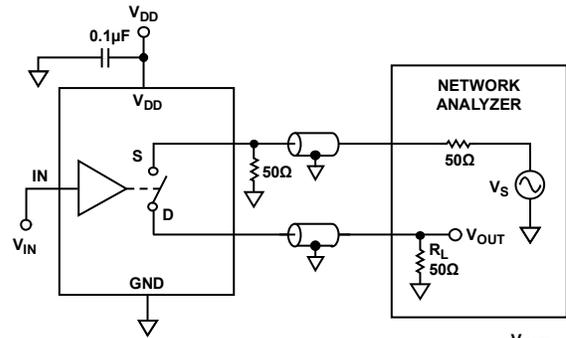


Figure 15. On Leakage

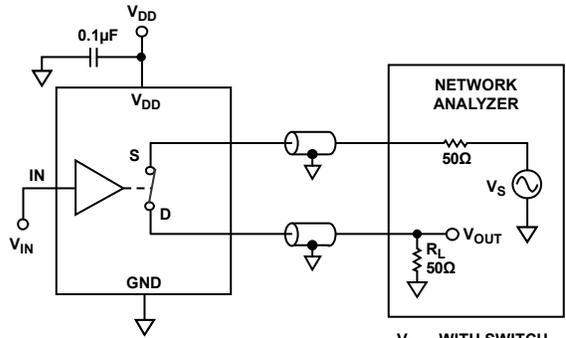
07793-015



$$\text{OFF ISOLATION} = 20 \log \frac{V_{\text{OUT}}}{V_s}$$

Figure 16. Off Isolation

07793-018



$$\text{INSERTION LOSS} = 20 \log \frac{V_{\text{OUT WITH SWITCH}}}{V_{\text{OUT WITHOUT SWITCH}}}$$

Figure 17. Bandwidth

07793-019

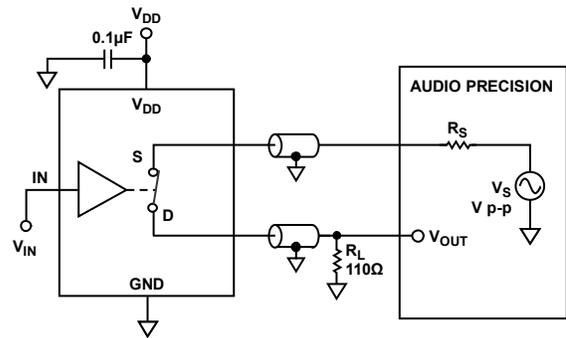


Figure 18. THD + Noise

07793-020

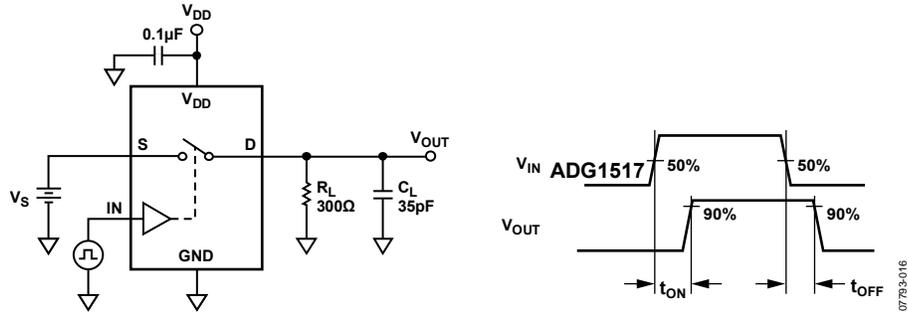


Figure 19. Switching Times

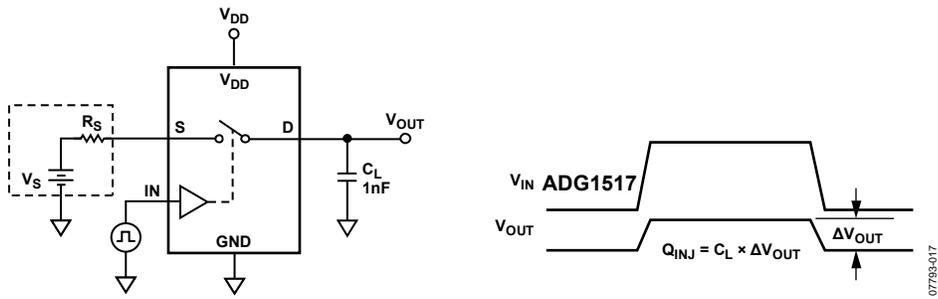


Figure 20. Charge Injection

## TERMINOLOGY

**I<sub>DD</sub>**

The positive supply current.

**V<sub>D</sub> (V<sub>S</sub>)**

The analog voltage on Terminal D and Terminal S.

**R<sub>ON</sub>**

The ohmic resistance between D and S.

**R<sub>FLAT(ON)</sub>**

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

**I<sub>S</sub> (Off)**

The source leakage current with the switch off.

**I<sub>D</sub> (Off)**

The drain leakage current with the switch off.

**I<sub>D</sub>, I<sub>S</sub> (On)**

The channel leakage current with the switch on.

**V<sub>INL</sub>**

The maximum input voltage for Logic 0.

**V<sub>INH</sub>**

The minimum input voltage for Logic 1.

**I<sub>INL</sub> (I<sub>INH</sub>)**

The input current of the digital input.

**C<sub>S</sub> (Off)**

The off switch source capacitance, measured with reference to ground.

**C<sub>D</sub> (Off)**

The off switch drain capacitance, measured with reference to ground.

**C<sub>D</sub>, C<sub>S</sub> (On)**

The on switch capacitance, measured with reference to ground.

**C<sub>IN</sub>**

The digital input capacitance.

**t<sub>ON</sub>**

Delay time between the 50% and 90% points of the digital input and switch on condition.

**t<sub>OFF</sub>**

Delay time between the 50% and 90% points of the digital input and switch off condition.

### **Charge Injection**

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

### **Off Isolation**

A measure of unwanted signal coupling through an off switch.

### **Bandwidth**

The frequency at which the output is attenuated by 3 dB.

### **On Response**

The frequency response of the on switch.

### **Insertion Loss**

The loss due to the on resistance of the switch.

### **THD + N**

The ratio of the harmonic amplitude plus noise of the signal to the fundamental.

### **ACPSRR (AC Power Supply Rejection Ratio)**

Measures the ability of a part to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p. The ratio of the amplitude of signal on the output to the amplitude of the modulation is the ACPSRR.

# OUTLINE DIMENSIONS

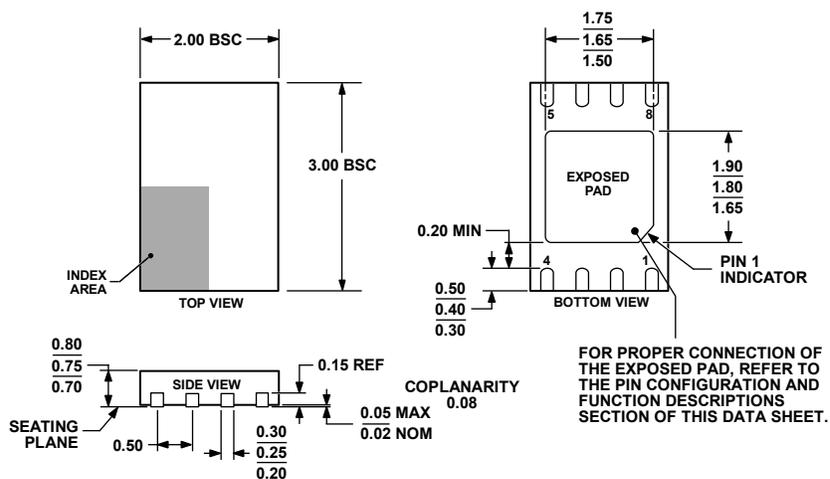


Figure 21. 8-Lead Lead Frame Chip Scale Package [LFCSP\_WD]  
 3 mm × 2 mm Body, Very Very Thin, Dual Lead  
 (CP-8-4)  
 Dimensions shown in millimeters

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding
ADG1517BCPZ-REEL7 <sup>1</sup>	-40°C to +125°C	8-Lead Lead Frame Chip Scale Package (LFCSP_WD)	CP-8-4	1E

<sup>1</sup> Z = RoHS Compliant Part.

**ADG1517**

**NOTES**